

### INCHANGE SEMICONDUCTOR

## isc N-Channel MOSFET Transistor

# FMH30N60S1FD

#### • FEATURES

- With TO-3PN packaging
- · High speed switching
- Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATIONS

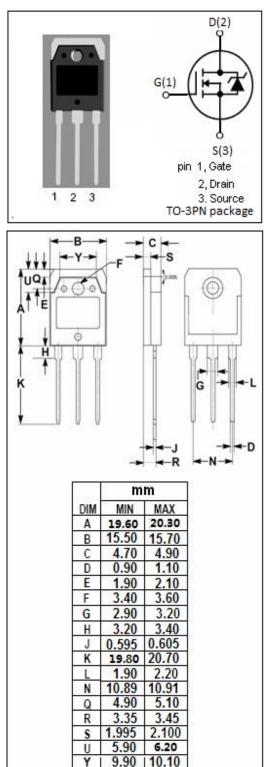
- · Power supply
- Switching applications

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)								
SYMBOL	PARAMETER	VALUE	UNIT					
V <sub>DSS</sub>	Drain-Source Voltage	600	V					
V <sub>GSS</sub>	Gate-Source Voltage	±30	∧v					
ID	Drain Current-Continuous@Tc=25℃ Tc=100℃	30 19	A					
I <sub>DM</sub>	Drain Current-Single Pulsed	90	А					
P <sub>D</sub>	Total Dissipation	220	W					
Tj	Operating Junction Temperature	-55~150	°C					
T <sub>stg</sub>	Storage Temperature	-55~150	°C					

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(ch-c) Channel-to-case thermal resistance		0.46	°C/W

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### isc website: www.iscsemi.cn

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#### **ELECTRICAL CHARACTERISTICS**

 $T_c=25^{\circ}C$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =0.25mA	600			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =±30V; I <sub>D</sub> =1.0mA	3.0		5.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =15A		111	132	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 600V; V <sub>GS</sub> = 0;			25	μA
VSDF	Diode forward voltage	I <sub>SD</sub> =30A; V <sub>GS</sub> = 0V			1.35	V

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